NSN 5961-00-226-8579

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View Online at https://aerobasegroup.com/nsn/5961-00-226-8579
Inclosure Material:
Metal
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 collector to base voltage/static/emitter open and 45.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
30.00 milliamperes source cutoff current
Power Rating Per Characteristic:
300.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/253 government specification
Shelf Life:
N/a
Unit Of Measure:

N

Demilitarization:

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